

M1 THRU M7



康比電子
HORNBY ELECTRONIC

SURFACE MOUNT PLASTIC SILICON RECTIFIER

REVERSE VOLTAGE: 50 to 1000 VOLTS

FORWARD CURRENT: 1.0 AMPERE

FEATURES

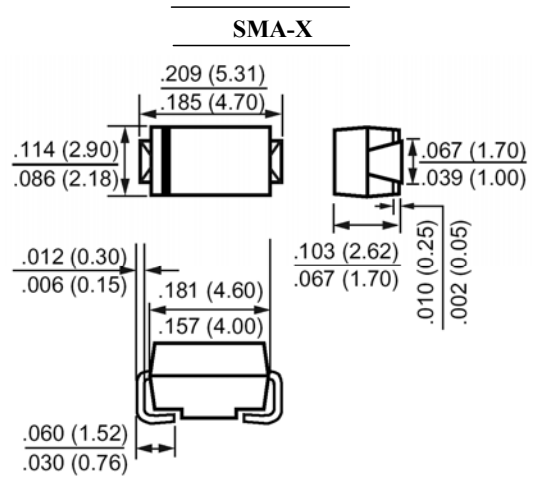
- Plastic package has Underwriters Laboratory Flammability Classification 94V-O
- For surface mounted applications
- Low profile package
- Easy pick and place
- Built-in strain relief
- Low forward voltage drop
- Suffix " H " indicated Halogen-free part, ex.M1H

MECHANICAL DATA

Case : Molded plastic, SMA-X

Terminals: Solder plated, solderable per MIL-STD-750, method 2026 guaranteed

Polarity : Color band denotes cathode end



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Parameter	Symbols	M1	M2	M3	M4	M5	M6	M7	Units
Maximum Recerrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at $T_J=75^\circ\text{C}$	$I_{(AV)}$	1.0							Amp
Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	30							Amp
Maximum Forward Voltage at 1.0A	V_F	1.10							Volts
Maximum Reverse Current at $T_J=25^\circ\text{C}$	I_R	5.0							uAmp
at Rated DC Blocking Voltage $T_J=125^\circ\text{C}$		100							
Typical Junction Capacitance (Note 1)	C_J	12							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	30							°C/W
Maximum Reverse Recovery Time (Note 3)	T_{RR}	2.5							µS
Operating Junction Temperature Range	T_J	-65 to +150							°C
Storage Temperature Range	T_{stg}	-65 to +150							°C

NOTES:

1- Measured at 1 MHz and applied reverse voltage of 4.0 VDC.

2- Thermal resistance from junction to ambient mounted on P.C.B. with 0.315 x 0.315" (8.0 x 8.0mm) copper pad areas

3- Reverse Recovery Test Conditions: $I_F=.5A$, $I_R=1A$, $I_{RR}=.25A$.

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RATINGS AND CHARACTERISTIC CURVES

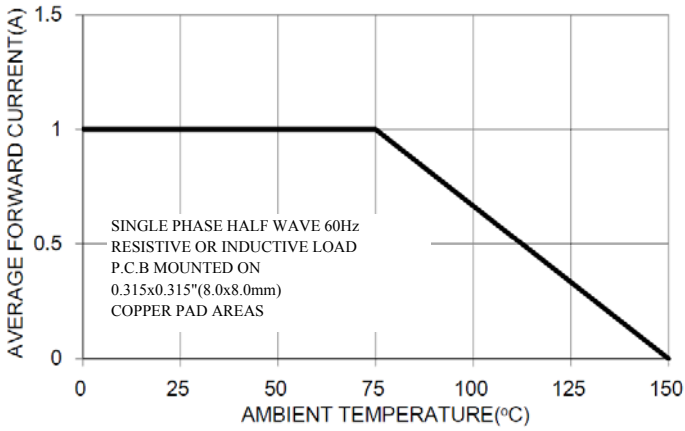


FIG. 1 MAXIMUM FORWARD CURRENT DERATING CURVE

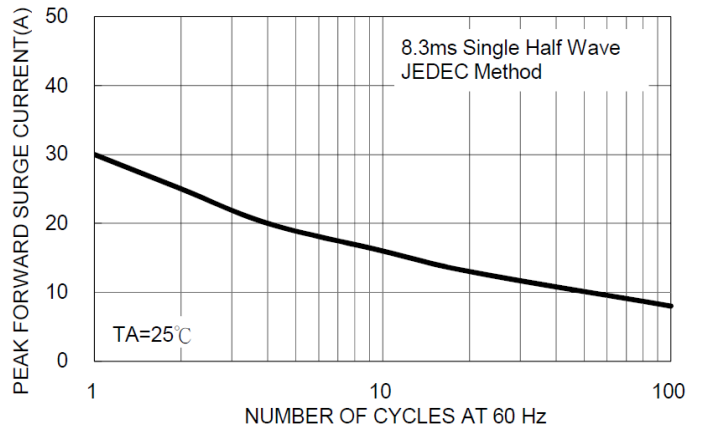


FIG. 2 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

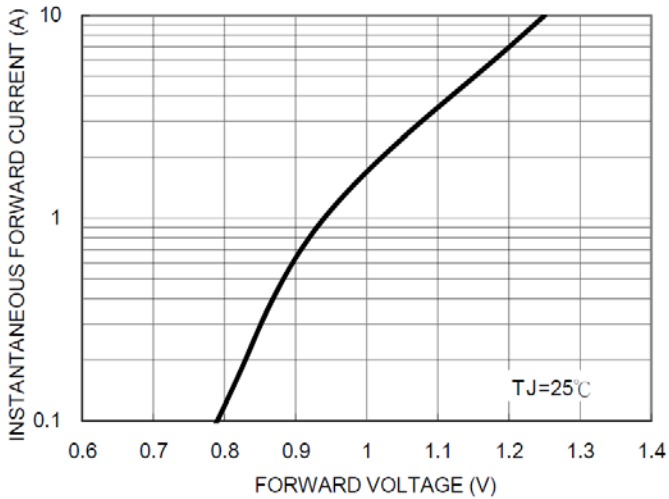


FIG. 3 TYPICAL FORWARD CHARACTERISTICS

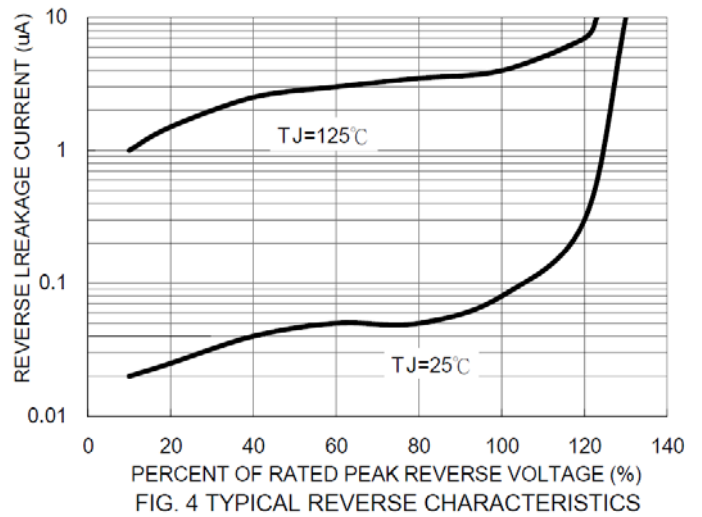


FIG. 4 TYPICAL REVERSE CHARACTERISTICS